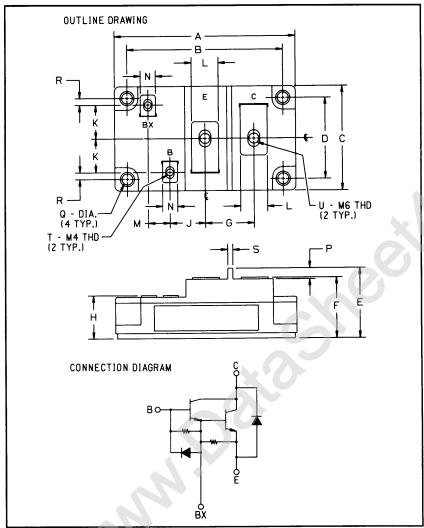


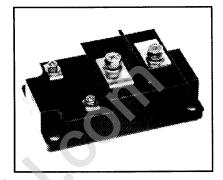
## Single Darlington Transistor Module 300 Amperes/600 Volts



## **Outline Drawing**

Dimensions	Inches	Millimeters		
Α	4.252 Max.	108 Max.		
В	3.661 ± 0.012	93 ± 0.3		
С	2.441 Max.	62 Max.		
D	1.890 ± 0.012	48 ± 0.3		
E	1.634 Max.	41.5 Max.		
F	1.417 Max.	36 Max.		
G	1.142	29		
Н	1.004	25.5		
J	0.827	21		
K	0.787	20		

Dimensions	Inches	Millimeters
L	0.630	16
М	0.512 13	
N	0.354	9
P	0.256	6.5
Q	0.256 Dia.	6.5 Dia.
R	0.157	4
S	0.118	3
T	M4 Metric M4	
U	M6 Metric	M6



## **Description:**

The Powerex Single Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of one Darlington Transistor with a reverse parallel connected highspeed diode and base-to-emitter speed-up diode.

#### Features:

Isolated Mounting
Planar Chips
Discrete Fast Recovery
Feedback Diode
High Gain (hFE)
Base-Emitter Speed-up Diode

#### **Applications:**

	p
	Inverters
	DC Motor Control
	Switching Power Supplies
Ē	AC Motor Control

## Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KS624430 is a 450 V<sub>CEO(sus)</sub> (600 V<sub>CEV</sub>), 300 Ampere Single Darlington Module.

Туре	V <sub>CEO(sus)</sub> Volts (X 10)	Current Rating Amperes (X 10)
KS62	45	30



KS624530 Single Darlington Transistor Module 300 Amperes/600 Volts

#### Absolute Maximum Ratings, T<sub>i</sub> = 25 °C unless otherwise specified

Ratings	Symbol	KS624530	Units
Junction Temperature	T <sub>i</sub>	-40 to 150	°C
Storage Temperature	T <sub>stg</sub>	-40 to 125	°C
Collector-Emitter Sustaining Voltage	V <sub>CEO(sus)</sub>	450	Volts
Collector-Emitter Sustaining Voltage, V <sub>BE</sub> = -2V	V <sub>CEV(sus)</sub>	600	Volts
Collector-Base Voltage	V <sub>CBO</sub>	600	Volts
Emitter-Base Voltage	V <sub>EBO</sub>	7	Volts
Collector-Emitter Voltage	V <sub>CEV</sub>	600	Volts
Continuous Collector Current	lo	300	Amperes
Diode Forward Current	I <sub>FM</sub>	300	Amperes
Continuous Base Current	I <sub>B</sub>	18	Amperes
Diode Surge Current	I <sub>FSM</sub>	3000	Amperes
Power Dissipation	Pt	1380	Watts
Max. Mounting Torque M6 Terminal Screws (E, C)	=	26	inlb.
Max. Mounting Torque M4 Terminal Screws (B, Bx)	<del>-</del>	12	inlb.
Max. Mounting Torque M6 Mounting Screws	-	26	inlb.
Modular Weight (Typical)	_	460	Grams
V Isolation	V <sub>RMS</sub>	2000	Volts

# Electrical Characteristics, $T_i$ = 25 °C unless otherwise specified

Characteristics		Symbol	Test Conditions	Min.	Тур.	Max.	Units
Collector Cutofi	Current	I <sub>CEV</sub>	V <sub>CE</sub> = 600V, V <sub>BE</sub> = -2V	_		4	mA
			V <sub>CE</sub> = 600V, V <sub>BE</sub> = -2V, T <sub>C</sub> = 125°C	-	_	30	mA
Emitter Cutoff C	Current	I <sub>EBO</sub>	V <sub>EB</sub> = 7V	_	_	700	mA
DC Current Ga	in	h <sub>FE</sub>	I <sub>C</sub> = 300A, V <sub>CE</sub> = 2.8V	75	_	-	_
			I <sub>C</sub> = 300A, V <sub>CE</sub> = 5.0V	100	_		_
Diode Forward	Voltage	V <sub>FM</sub>	I <sub>FM</sub> = 300A	_	_	1.85	Volts
Collector-Emitte	er Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 300A, I <sub>B</sub> = 4.0A	_	_	2.0	Voits
Base-Emitter S	aturation Voltage	V <sub>BE(sat)</sub>	$I_C = 300A$ , $I_B = 4.0A$	_	_	2.5	Volts
Resistive	Turn-on	t <sub>on</sub>	V <sub>CC</sub> = 300V	-	_	2.5	μS
Load	Storage Time	t <sub>s</sub>	I <sub>C</sub> = 300A	-	_	12	μS
Switch Times	Fall Time	t <sub>f</sub>	I <sub>B1</sub> = 6A, I <sub>B2</sub> = -6A	_	_	3.0	μs

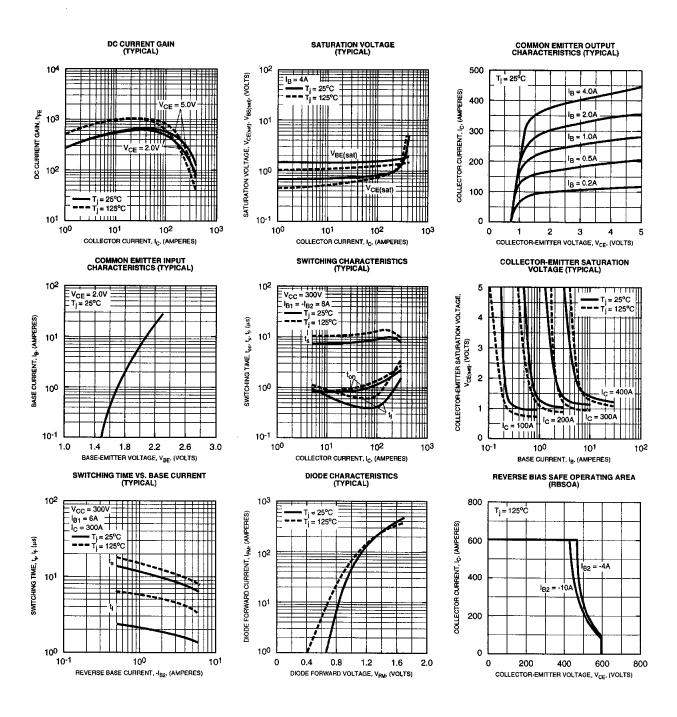
#### Thermal and Mechanical Characteristics, T<sub>i</sub> = 25 °C unless otherwise specified

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Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Thermal Resistance, Case-to-Sink	R <sub>e(c-s)</sub>	<b>-</b> ,		_	0.04	°C/W
Thermal Resistance, Junction-to-Case	R <sub>e(j-c)</sub>	Transistor Part	_	_	0.09	°C/W
Thermal Resistance, Junction-to-Case	R <sub>e(j-c)</sub>	Diode Part	-	-	0.3	°C/W



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